

RELIABILITY REPORT
FOR
MAX4739Exx
PLASTIC ENCAPSULATED/CHIP SCALE DEVICES

January 12, 2004

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

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Conclusion

The MAX4739 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

Table of Contents

I.Device Description	V.Quality Assurance Information
II.Manufacturing Information	VI.Reliability Evaluation
III.Packaging Information	
IV.Die InformationAttachments

I. Device Description

A. General

The MAX4739 low-voltage, low on-resistance (R_{ON}), quad single-pole/single throw (SPST) analog switch operates from a single +1.8V to +5.5V supply. This device is designed for USB 1.1 and audio switching applications.

The MAX4739 features 4.5Ω R_{ON} (max) with 1.2Ω flatness and 0.4Ω matching between channels. This new switch features guaranteed operation from +1.8V to +5.5V and is fully specified at 3V and 5V. This switch offers break-before-make switching (1ns) with $t_{ON} < 80ns$ and $t_{OFF} < 40ns$ at +2.7V. The digital logic inputs are +1.8V logic compatible with a +2.7V to +3.6V supply.

This switch is packaged in a chip-scale package (UCSP™), significantly reducing the required PC board area. The chip occupies only a 2mm x 2mm area and has a 4 x 4 bump array with a bump pitch of 0.5mm. This switch is also available in a 14-pin TSSOP package.

B. Absolute Maximum Ratings

<u>Item</u>	<u>Rating</u>
(All Voltages Referenced to GND)	
V+, IN_	-0.3V to +6.0V
COM_, NO_, NC_ (Note 1)	-0.3V to (V+ + 0.3V)
Continuous Current COM_, NO_, NC_	±100mA
Peak Current COM_, NO_, NC_ (pulsed at 1ms, 10% duty cycle)	±200mA
Operating Temperature Range	-40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Bump Temperature (soldering) (Note 2)	
Infrared (15s)	+220°C
Vapor Phase (60s)	+215°C
Continuous Power Dissipation (TA = +70°C)	
14-Pin TSSOP	500mW
16-Bump UCSP	659mW
Derates above +70°C	
14-Pin TSSOP	6.3mW/°C
16-Bump UCSP	8.3mW/°C

Note 1: Signals on COM_, NO_, or NC_ exceeding V+ or GND are clamped by internal diodes. Limit forward-diode current to maximum

Note 2: This device is constructed using a unique set of packaging techniques that impose a limit on the thermal profile the device can be exposed to during board level solder attach and rework. This limit permits only the use of the solder profiles recommended in the industry standard specification, JEDEC 020A, paragraph 7.6, table 3 for IR/VPFR and convection reflow. Preheating is required. Hand or wave soldering is not allowed.

II. Manufacturing Information

A. Description/Function:	4.5 ? Quad SPST Analog Switches
B. Process:	S8
C. Number of Device Transistors:	361
D. Fabrication Location:	California, USA
E. Assembly Location:	Philippines or Thailand
F. Date of Initial Production:	October, 2002

III. Packaging Information

A. Package Type:	14-Lead TSSOP	16-Bump UCSP
B. Lead Frame:	Copper	N/A
C. Lead Finish:	Solder Plate	N/A
D. Die Attach:	Silver-Filled Epoxy	N/A
E. Bondwire:	Gold (1.0 mil dia.)	N/A
F. Mold Material:	Epoxy with silica filler	N/A
G. Assembly Diagram:	# 05-9000-0209	# 05-9000-0210
H. Flammability Rating:	Class UL94-V0	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard JESD22-A112:	Level 1	Level 1

IV. Die Information

A. Dimensions:	83 x 83 mils
B. Passivation:	Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Aluminum/Copper/Silicon
D. Backside Metallization:	None
E. Minimum Metal Width:	.8 microns (as drawn)
F. Minimum Metal Spacing:	.8 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

A. Quality Assurance Contacts:

Jim Pedicord (Manager, Rel Operations)
Bryan Preeshl (Executive Director of QA)
Kenneth Huening (Vice President)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm

D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4389 \times 44 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

└ Thermal acceleration factor assuming a 0.8eV activation energy

$$\lambda = 24.68 \times 10^{-9} \quad \lambda = 24.68 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure the reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on lots exceeding this level. The following Burn-In Schematic (Spec. #06-5880) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (**RR-1M**).

B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

C. E.S.D. and Latch-Up Testing

The AS12-2 die type has been found to have all pins able to withstand a transient pulse of +/-1500V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of $\pm 250\text{mA}$.

Table 1
Reliability Evaluation Test Results

MAX4739Exx

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test (Note 1)					
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		44	0
Moisture Testing (Note 2)					
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	TSSOP	77	0
			UCSP	77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality	TSSOP	77	0
			UCSP	N/A	N/A
Mechanical Stress (Note 2)					
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010 (Note 3)	DC Parameters & functionality	TSSOP	77	0
			UCSP	77	0

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data

Note 3: UCSP Temperature Cycle performed at -40°C/125°C, 1000 Cycles, ramp rate 11°C/minute, dwell=15 minutes,
One cycle/hour

Attachment #1

TABLE II. Pin combination to be tested. 1/ 2/

	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V_{PS1} 3/	All V_{PS1} pins
2.	All input and output pins	All other input-output pins

1/ Table II is restated in narrative form in 3.4 below.

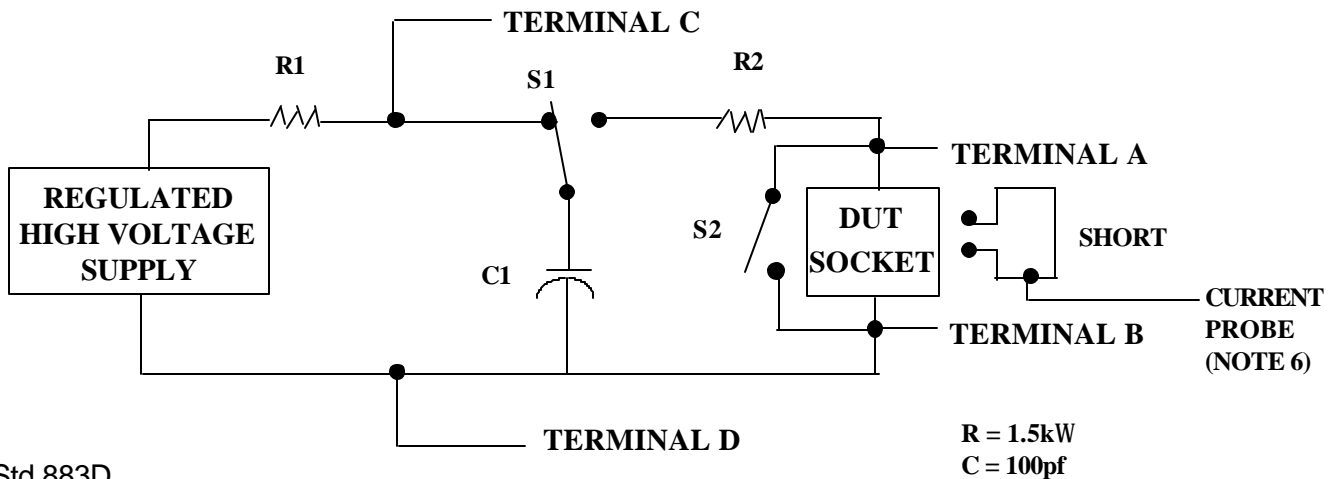
2/ No connects are not to be tested.

3/ Repeat pin combination I for each named Power supply and for ground

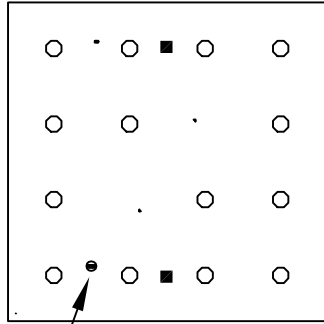
(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_S$, $-V_S$, V_{REF} , etc).

3.4 Pin combinations to be tested.

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V_{SS1} , or V_{SS2} or V_{SS3} or V_{CC1} , or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



ORIGINAL CHIP



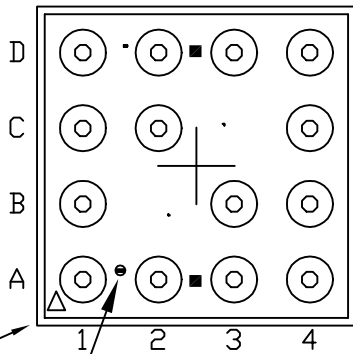
DIE I.D.

NORTH

WEST

EAST

AFTER BUMP

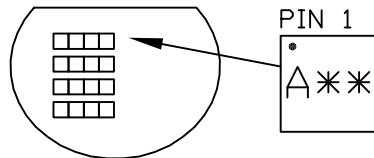


PIN 1

DIE I.D.

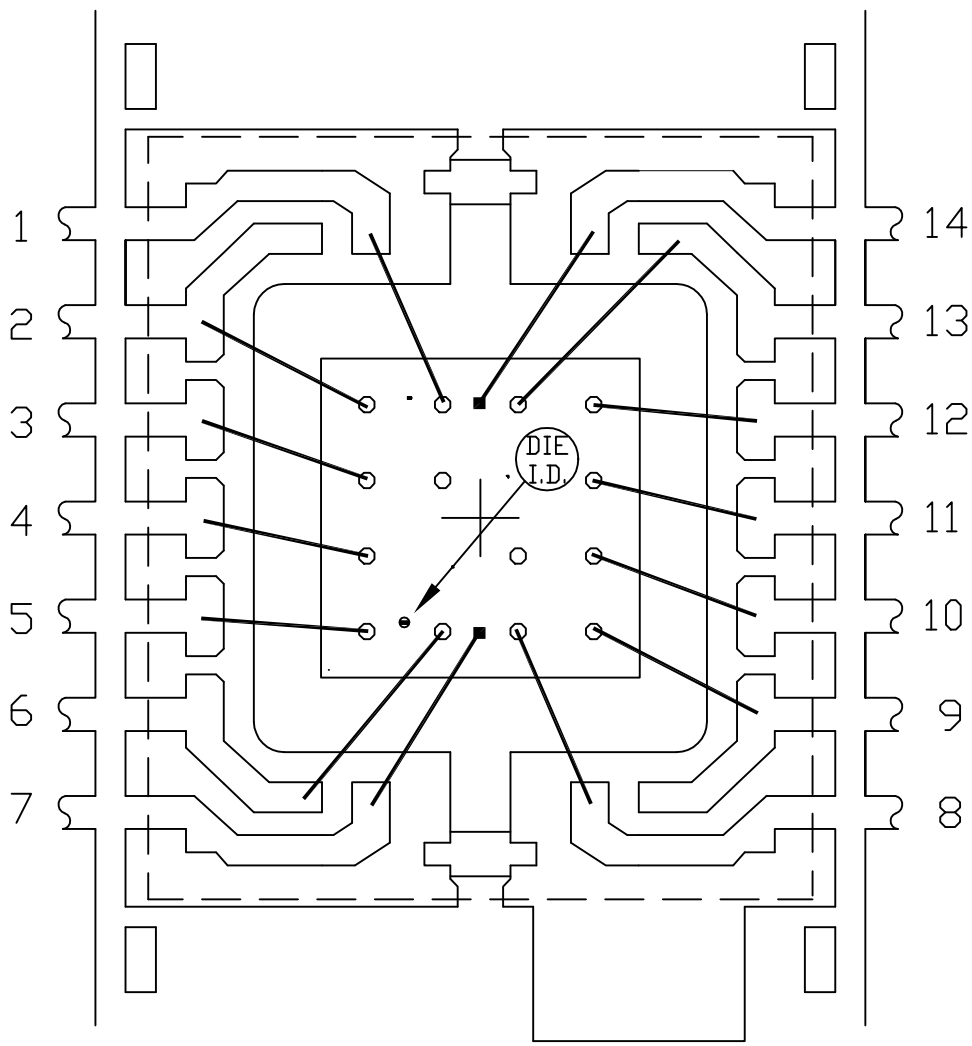
SOUTH

SELECT THE BOX INDICATING THE WAFER FLAT SIDE WITH RESPECT TO PIN 1.



PART MARKING ORIENTATION
IN REFERENCE TO WAFER FLAT
(MARK IS ON WAFER BACKSIDE)

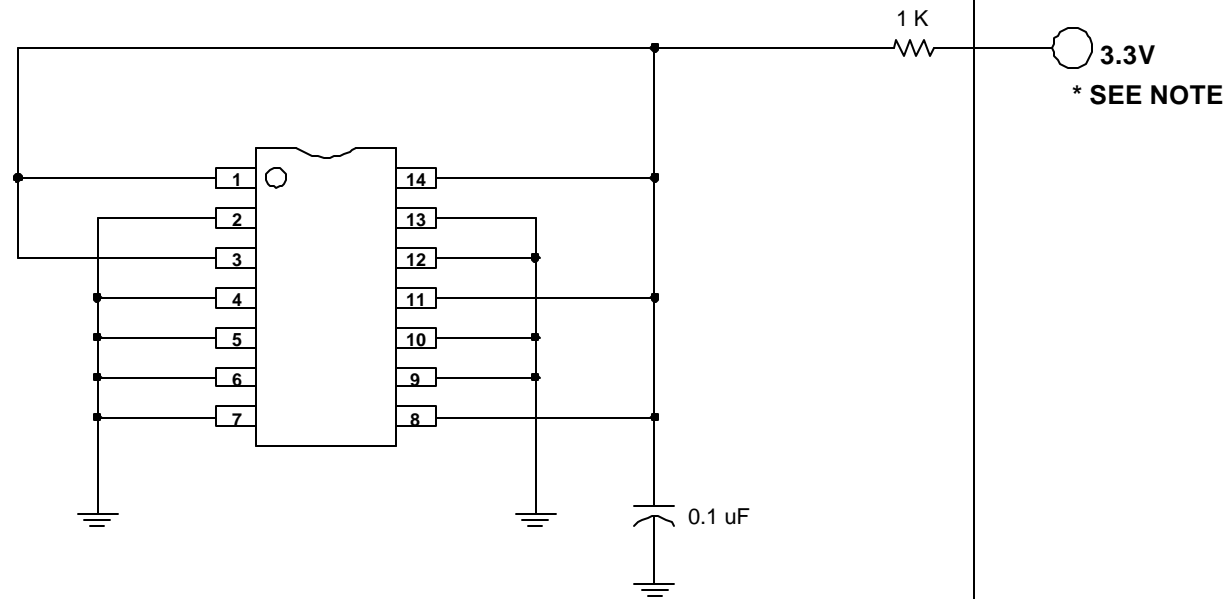
PKG. CODE: B16-4		SIGNATURES	DATE	MAXIM CONFIDENTIAL & PROPRIETARY	
CAV./PAD SIZE: N/A	PKG. DESIGN			BOND DIAGRAM #: 05-9000-0210	REV: A



PKG. CODE: U14-1		SIGNATURES	DATE	 CONFIDENTIAL & PROPRIETARY	
CAV./PAD SIZE: 118x122	PKG. DESIGN			BOND DIAGRAM #: 05-9000-0209	REV: A

ONCE PER SOCKET

ONCE PER BOARD



DEVICE S = MAX4751/4737
PACKAGE: 14-TSSOP
MAX. EXPECTED CURRENT = 1uA

NOTES: * For MAX4737 use +5v input w/jumper to +5v edge pin.